

## 1.Description

The UMW TSV631 devices are single operational amplifiers offering low voltage, low power operation and rail-to-rail input and output. These devices have a very low input bias current and a low offset voltage making them ideal for applications that require precision. They can operate at power supplies ranging from 1.5 V to 5.5 V, and are therefore very suitable for battery powered devices, extending battery life.

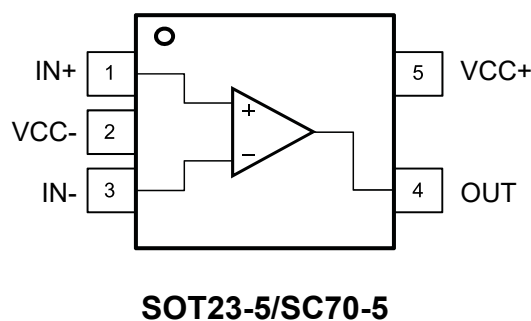
## 2.Features

- Low offset voltage: 500 $\mu$ V max (A version)
- Low power consumption: 60  $\mu$ A typ at 5 V
- Low supply voltage: 1.5 V - 5.5 V
- Gain bandwidth product: 880 kHz typ
- Unity gain stability
- Low power shutdown mode: 5nA typ
- High output current: 63 mA at  $V_{CC}=5V$
- Low input bias current: 1pA typ
- Rail-to-rail input and output
- Extended temperature range: -40°C to 125°C

## 3.Applications

- Battery-powered applications
- Portable devices
- Active filtering
- Medical instrumentation

## 4.Pinning information





## 5. Absolute Maximum Ratings

| Parameter                              |         | Symbol     | Value                              | Units          |
|----------------------------------------|---------|------------|------------------------------------|----------------|
| Supply voltage                         |         | $V_{CC}$   | 6                                  | V              |
| Differential input voltage             |         | $V_{id}$   | $\pm V_{CC}$                       | V              |
| Input voltage                          |         | $V_{in}$   | $(V_{CC-})-0.2$ to $(V_{CC+})+0.2$ | V              |
| Input current                          |         | $I_{in}$   | 10                                 | mA             |
| Shutdown voltage                       |         | SHDN       | 6                                  | V              |
| Storage temperature                    |         | $T_{STG}$  | -65 to 150                         | $^{\circ}$ C   |
| Maximum junction temperature           |         | $T_J$      | 150                                | $^{\circ}$ C   |
| Thermal resistance junction-to-ambient | SC70-5  | $R_{thja}$ | 205                                | $^{\circ}$ C/W |
|                                        | SOT23-5 |            | 250                                | $^{\circ}$ C/W |

## 6. Operating conditions

| Parameter                            | Symbol     | Rating                             | Units        |
|--------------------------------------|------------|------------------------------------|--------------|
| Supply voltage                       | $V_{CC}$   | 1.5 to 5.5                         | V            |
| Common mode input voltage range      | $V_{icm}$  | $(V_{CC-})-0.1$ to $(V_{CC+})+0.1$ | V            |
| Operating free air temperature range | $T_{oper}$ | 40 to +125                         | $^{\circ}$ C |



## 7.1 Electrical Characteristics

( $V_{CC+}$ )=1.8V with ( $V_{CC-}$ )=0V,  $V_{icm}=V_{CC}/2$ ,  $T_{amb}=25^{\circ}\text{C}$ , and  $R_L$  connected to  $V_{CC}/2$  (unless otherwise specified)

| Parameter                                                                       | Symbol               | Conditions                                           | Min | Typ | Max | Units |
|---------------------------------------------------------------------------------|----------------------|------------------------------------------------------|-----|-----|-----|-------|
| Offset voltage                                                                  | V <sub>io</sub>      | UMW TSV631                                           |     |     | 3   | mV    |
|                                                                                 |                      | UMW TSV631A                                          |     |     | 0.5 | mV    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C, UMW TSV631             |     |     | 4.5 | mV    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C, UMW TSV631A            |     |     | 2   | mV    |
| Input offset voltage drift                                                      | ΔV <sub>io</sub> /ΔT |                                                      |     | 2   |     | μV/°C |
| Input offset current, V <sub>out</sub> =V <sub>CC</sub> /2                      | I <sub>io</sub>      | -40°C<T <sub>op</sub> <125°C                         |     | 1   | 10  | pA    |
|                                                                                 |                      |                                                      |     | 1   | 100 | pA    |
| Input bias current, V <sub>out</sub> =V <sub>CC</sub> /2                        | I <sub>ib</sub>      | -40°C<T <sub>op</sub> <125°C                         |     | 1   | 10  | pA    |
|                                                                                 |                      |                                                      |     | 1   | 100 | pA    |
| Common mode rejection ratio, 20 log (ΔV <sub>ic</sub> /ΔV <sub>io</sub> )       | CMR                  | 0V to 1.8V, V <sub>out</sub> =0.9V                   | 53  | 74  |     | dB    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         | 51  |     |     | dB    |
| Large signal voltage gain                                                       | A <sub>vd</sub>      | R <sub>L</sub> =10kΩ, V <sub>out</sub> =0.5V to 1.3V | 85  | 95  |     | dB    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         | 80  |     |     | dB    |
| High-level output voltage<br>V <sub>OH</sub> =V <sub>CC</sub> -V <sub>out</sub> | V <sub>OH</sub>      | R <sub>L</sub> =10kΩ                                 |     | 5   | 35  | mV    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         |     |     | 50  | mV    |
| Low-level output voltage                                                        | V <sub>OL</sub>      | R <sub>L</sub> =10kΩ                                 |     | 4   | 35  | mV    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         |     |     | 50  | mV    |
| I <sub>sink</sub>                                                               | I <sub>OUT</sub>     | V <sub>O</sub> =1.8V                                 | 6   | 12  |     | mA    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         | 4   |     |     | mA    |
| I <sub>source</sub>                                                             |                      | V <sub>out</sub> =0V                                 | 6   | 10  |     | mA    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         | 4   |     |     | mA    |
| Supply current<br>SHDN=V <sub>CC+</sub>                                         | I <sub>CC</sub>      | No load, V <sub>out</sub> =V <sub>CC</sub> /2        | 40  | 50  | 60  | μA    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         |     |     | 62  | μA    |



Rail-to-rail input/output, 60  $\mu$ A, 880 kHz, 5V  
CMOS operational amplifiers

| Parameter                      | Symbol   | Conditions                                | Min | Typ  | Max | Units           |
|--------------------------------|----------|-------------------------------------------|-----|------|-----|-----------------|
| Gain bandwidth product         | GBP      | $R_L=2k\Omega$ , $C_L=100pF$ , $f=100kHz$ | 700 | 790  |     | kHz             |
| Phase margin                   | $\phi_m$ | $R_L=2k\Omega$ , $C_L=100pF$              |     | 48   |     | Degrees         |
| Gain margin                    | $G_m$    |                                           |     | 11   |     | dB              |
| Slew rate                      | SR       | $R_L=2k\Omega$ , $C_L=100pF$ , $A_v=1$    | 0.2 | 0.27 |     | V/ $\mu$ s      |
| Equivalent input noise voltage | $e_n$    | $f=1kHz$                                  |     | 67   |     | nV/ $\sqrt{Hz}$ |
|                                |          | $f=10kHz$                                 |     | 53   |     | nV/ $\sqrt{Hz}$ |



## 7.2 Electrical Characteristics

Shutdown characteristics  $V_{CC}=1.8V$

| Parameter                                       | Symbol      | Conditions                                   | Min | Typ | Max | Units   |
|-------------------------------------------------|-------------|----------------------------------------------|-----|-----|-----|---------|
| Supply current in shutdown mode (all operators) | $I_{CC}$    | SHDN= $V_{CC-}$                              |     | 2.5 | 50  | nA      |
|                                                 |             | $-40^{\circ}C < T_{op} < 85^{\circ}C$        |     |     | 200 | nA      |
|                                                 |             | $-40^{\circ}C < T_{op} < 125^{\circ}C$       |     |     | 1.5 | $\mu$ A |
| Amplifier turn-on time                          | $t_{on}$    | $R_L=2k\Omega$                               |     | 300 |     | ns      |
| Amplifier turn-off time                         | $t_{off}$   | $V_{out}=(V_{CC-})+0.2V$ to $(V_{CC+})-0.2V$ |     | 20  |     | ns      |
| SHDN logic high                                 | $V_{IH}$    |                                              | 1.3 |     |     | V       |
| SHDN logic low                                  | $V_{IL}$    |                                              |     |     | 0.5 | V       |
| SHDN current high                               | $I_{IH}$    | SHDN= $V_{CC+}$                              |     | 10  |     | pA      |
| SHDN current low                                | $I_{IL}$    | SHDN= $V_{CC-}$                              |     | 10  |     | pA      |
| Output leakage in shutdown mode                 | $I_{OLeak}$ | SHDN= $V_{CC-}$                              |     | 50  |     | pA      |
|                                                 |             | $-40^{\circ}C < T_{op} < 125^{\circ}C$       |     | 1   |     | nA      |



## 7.3 Electrical Characteristics

( $V_{CC+}$ )=3.3V with ( $V_{CC-}$ )=0V,  $V_{icm}=V_{CC}/2$ ,  $T_{amb}=25^{\circ}\text{C}$ , and  $R_L$  connected to  $V_{CC}/2$  (unless otherwise specified)

| Parameter                                                                       | Symbol               | Conditions                                           | Min | Typ | Max | Units |
|---------------------------------------------------------------------------------|----------------------|------------------------------------------------------|-----|-----|-----|-------|
| Offset voltage                                                                  | V <sub>io</sub>      | UMW TSV631                                           |     |     | 3   | mV    |
|                                                                                 |                      | UMW TSV631A                                          |     |     | 0.5 | mV    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C, UMW TSV631             |     |     | 4.5 | mV    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C, UMW TSV631A            |     |     | 2   | mV    |
| Input offset voltage drift                                                      | ΔV <sub>io</sub> /ΔT |                                                      |     | 2   |     | μV/°C |
| Input offset current                                                            | I <sub>io</sub>      | -40°C<T <sub>op</sub> <125°C                         |     | 1   | 10  | pA    |
|                                                                                 |                      |                                                      |     | 1   | 100 | pA    |
| Input bias current                                                              | I <sub>ib</sub>      | -40°C<T <sub>op</sub> <125°C                         |     | 1   | 10  | pA    |
|                                                                                 |                      |                                                      |     | 1   | 100 | pA    |
| Common mode rejection ratio, 20 log (ΔV <sub>ic</sub> /ΔV <sub>io</sub> )       | CMR                  | 0V to 3.3V, V <sub>out</sub> =1.75V                  | 57  | 79  |     | dB    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         | 53  |     |     | dB    |
| Large signal voltage gain                                                       | A <sub>vd</sub>      | R <sub>L</sub> =10kΩ, V <sub>out</sub> =0.5V to 2.8V | 88  | 98  |     | dB    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         | 83  |     |     | dB    |
| High-level output voltage<br>V <sub>OH</sub> =V <sub>CC</sub> -V <sub>out</sub> | V <sub>OH</sub>      | R <sub>L</sub> =10kΩ                                 |     | 6   | 35  | mV    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         |     |     | 50  | mV    |
| Low-level output voltage                                                        | V <sub>OL</sub>      | R <sub>L</sub> =10kΩ                                 |     | 7   | 35  | mV    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         |     |     | 50  | mV    |
| I <sub>sink</sub>                                                               | I <sub>OUT</sub>     | V <sub>O</sub> =3.3V                                 | 30  | 45  |     | mA    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         | 25  | 42  |     | mA    |
| I <sub>source</sub>                                                             |                      | V <sub>out</sub> =0V                                 | 30  | 38  |     | mA    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         | 25  |     |     | mA    |
| Supply current<br>SHDN=V <sub>CC</sub> +                                        | I <sub>CC</sub>      | No load, V <sub>out</sub> =1.75V                     | 43  | 55  | 64  | μA    |
|                                                                                 |                      | -40°C<T <sub>op</sub> <125°C                         |     |     | 66  | μA    |



Rail-to-rail input/output, 60  $\mu$ A, 880 kHz, 5V  
CMOS operational amplifiers

| Parameter                      | Symbol   | Conditions                                | Min  | Typ  | Max | Units           |
|--------------------------------|----------|-------------------------------------------|------|------|-----|-----------------|
| Gain bandwidth product         | GBP      | $R_L=2k\Omega$ , $C_L=100pF$ , $f=100kHz$ | 710  | 860  |     | kHz             |
| Phase margin                   | $\phi_m$ | $R_L=2k\Omega$ , $C_L=100pF$              |      | 50   |     | Degrees         |
| Gain margin                    | $G_m$    |                                           |      | 11   |     | dB              |
| Slew rate                      | SR       | $R_L=2k\Omega$ , $C_L=100pF$ , $A_v=1$    | 0.22 | 0.29 |     | V/ $\mu$ s      |
| Equivalent input noise voltage | $e_n$    | $f=1kHz$                                  |      | 64   |     | nV/ $\sqrt{Hz}$ |
|                                |          | $f=10kHz$                                 |      | 51   |     | nV/ $\sqrt{Hz}$ |



## 7.4 DC Electrical Characteristics

( $V_{CC+}$ )=5V with ( $V_{CC-}$ )=0V,  $V_{icm}=V_{CC}/2$ ,  $T_{amb}=25^{\circ}\text{C}$ , and  $R_L$  connected to  $V_{CC}/2$  (unless otherwise specified)

| Parameter                                                                        | Symbol           | Conditions                                           | Min | Typ | Max  | Units |
|----------------------------------------------------------------------------------|------------------|------------------------------------------------------|-----|-----|------|-------|
| Offset voltage                                                                   | V <sub>io</sub>  | UMW TSV631                                           |     |     | 3    | mV    |
|                                                                                  |                  | UMW TSV631A                                          |     |     | 0.5  | mV    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C, UMW TSV631             |     |     | 4.5  | mV    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C, UMW TSV631A            |     |     | 2    | mV    |
| Input offset voltage drift                                                       | DV <sub>io</sub> |                                                      |     | 2   |      | μV/°C |
| Input offset current                                                             | I <sub>io</sub>  | -40°C<T <sub>op</sub> <125°C                         |     | 1   | 10   | pA    |
|                                                                                  |                  |                                                      |     | 1   | 100  | pA    |
| Input bias current                                                               | I <sub>ib</sub>  | -40°C<T <sub>op</sub> <125°C                         |     | 1   | 10   | pA    |
|                                                                                  |                  |                                                      |     | 1   | 100  | pA    |
| Common mode rejection ratio, 20 log (ΔV <sub>ic</sub> /ΔV <sub>io</sub> )        | CMR              | 0V to 5V, V <sub>out</sub> =2.5V                     | 60  | 80  |      | dB    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C                         | 55  |     |      | dB    |
| Supply voltage rejection ratio<br>20 log, ΔV <sub>CC</sub> /ΔV <sub>io</sub>     | SVR              | V <sub>CC</sub> =1.8 to 5V                           | 75  | 102 |      | dB    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C                         |     |     |      | dB    |
| Large signal voltage gain                                                        | A <sub>vd</sub>  | R <sub>L</sub> =10kΩ, V <sub>out</sub> =0.5V to 4.5V | 89  | 98  |      | dB    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C                         | 84  |     |      | dB    |
| High level output voltage<br>V <sub>OH</sub> =V <sub>CC</sub> - V <sub>out</sub> | V <sub>OH</sub>  | R <sub>L</sub> =10kΩ                                 |     | 7   | 35   | mV    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C                         |     |     | 5035 | mV    |
| Low level output voltage                                                         | V <sub>OL</sub>  | R <sub>L</sub> =10kΩ                                 |     | 6   | 50   | mV    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C                         |     |     |      | mV    |
| I <sub>sink</sub>                                                                | I <sub>OUT</sub> | V <sub>O</sub> =5V                                   | 40  | 69  |      | mA    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C                         | 35  | 65  |      | mA    |
| I <sub>source</sub>                                                              |                  | V <sub>out</sub> =0V                                 | 40  | 74  |      | mA    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C                         | 36  | 68  |      | mA    |
| Supply current<br>SHDN=V <sub>CC+</sub>                                          | I <sub>CC</sub>  | No load, V <sub>out</sub> =V <sub>CC</sub> /2        | 50  | 60  | 69   | μA    |
|                                                                                  |                  | -40°C<T <sub>op</sub> <125°C                         |     |     | 72   | μA    |



Rail-to-rail input/output, 60  $\mu$ A, 880 kHz, 5V  
CMOS operational amplifiers

| Parameter                      | Symbol     | Conditions                                                                        | Min  | Typ    | Max | Units           |
|--------------------------------|------------|-----------------------------------------------------------------------------------|------|--------|-----|-----------------|
| Gain bandwidth product         | GBP        | $R_L=2k\Omega$ , $C_L=100pF$ , $f=100kHz$                                         | 730  | 880    |     | kHz             |
| Unity gain frequency           | $F_u$      | $R_L=2k\Omega$ , $C_L=100pF$                                                      |      | 830    |     | kHz             |
| Phase margin                   | $\phi_m$   |                                                                                   |      | 50     |     | Degrees         |
| Gain margin                    | $G_m$      |                                                                                   |      | 12     |     | dB              |
| Slew rate                      | SR         | $R_L=2k\Omega$ , $C_L=100pF$ , $A_v=1$                                            | 0.25 | 0.34   |     | V/ $\mu$ s      |
| Equivalent input noise voltage | $e_n$      | $f=1kHz$                                                                          |      | 60     |     | nV/ $\sqrt{Hz}$ |
|                                |            | $f=10kHz$                                                                         |      | 47     |     | nV/ $\sqrt{Hz}$ |
| Total harmonic distortion      | THD+ $e_n$ | $f=1kHz$ , $A_v=1$ , $R_L=100k\Omega$ ,<br>$V_{icm}=V_{CC}/2$ , $V_{out}=2V_{PP}$ |      | 0.0017 |     | %               |



## 7.5 Electrical Characteristics

Shutdown characteristics  $V_{CC}=5V$

| Parameter                                       | Symbol      | Conditions                                   | Min | Typ | Max | Units   |
|-------------------------------------------------|-------------|----------------------------------------------|-----|-----|-----|---------|
| Supply current in shutdown mode (all operators) | $I_{CC}$    | SHDN= $V_{CC-}$                              |     | 5   | 50  | nA      |
|                                                 |             | $-40^{\circ}C < T_{op} < 85^{\circ}C$        |     |     | 200 | nA      |
|                                                 |             | $-40^{\circ}C < T_{op} < 125^{\circ}C$       |     |     | 1.5 | $\mu$ A |
| Amplifier turn-on time                          | $t_{on}$    | $R_L=2k\Omega$                               |     | 300 |     | ns      |
| Amplifier turn-off time                         | $t_{off}$   | $V_{out}=(V_{CC-})+0.2V$ to $(V_{CC+})-0.2V$ |     | 30  |     | ns      |
| SHDN logic high                                 | $V_{IH}$    |                                              | 4.5 |     |     | V       |
| SHDN logic low                                  | $V_{IL}$    |                                              |     |     | 0.5 | V       |
| SHDN current high                               | $I_{IH}$    | SHDN= $V_{CC+}$                              |     | 10  |     | pA      |
| SHDN current low                                | $I_{IL}$    | SHDN= $V_{CC-}$                              |     | 10  |     | pA      |
| Output leakage in shutdown mode                 | $I_{OLeak}$ | SHDN= $V_{CC-}$                              |     | 50  |     | pA      |
|                                                 |             | $-40^{\circ}C < T_{op} < 125^{\circ}C$       |     | 1   |     | nA      |



## 8.1 Typical characteristic

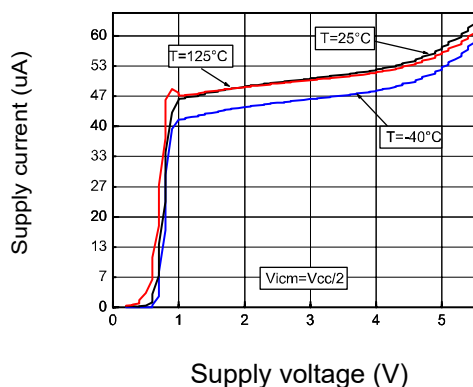


Figure 1: Supply current vs. supply voltage at  $V_{ictm} = V_{CC}/2$

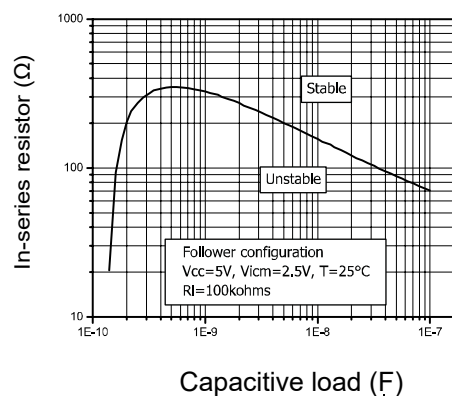


Figure 2: In-series resistor ( $R_{iso}$ ) vs. capacitive load

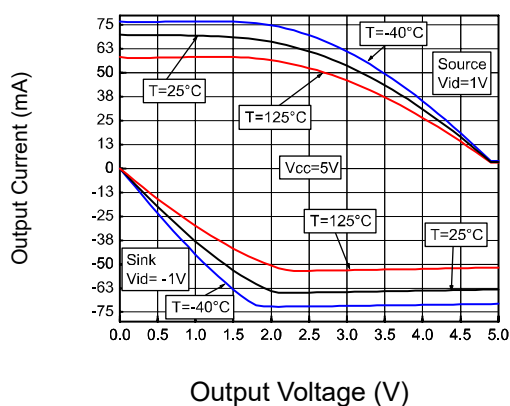


Figure 3: Output current vs. output voltage at  $V_{CC}=5V$

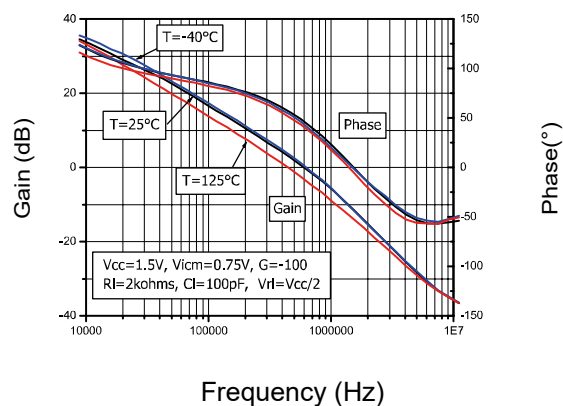


Figure 4: Voltage gain and phase vs. frequency at  $V_{CC}=1.5V$

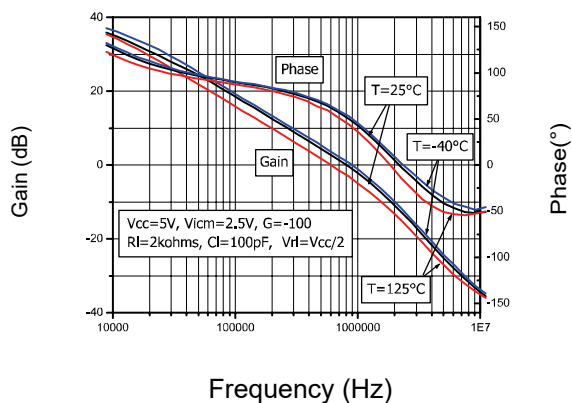


Figure 5: Voltage gain and phase vs. frequency at  $V_{CC}=5V$

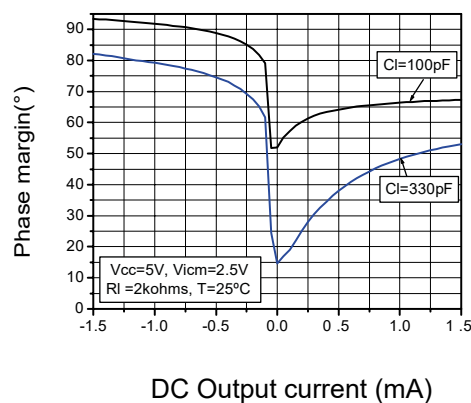


Figure 6: Phase margin vs. output current at  $V_{CC}=5V$



## 8.2 Typical characteristic

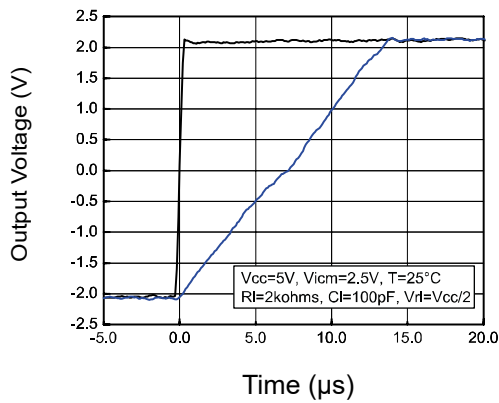


Figure 7: Positive slew rate vs. time

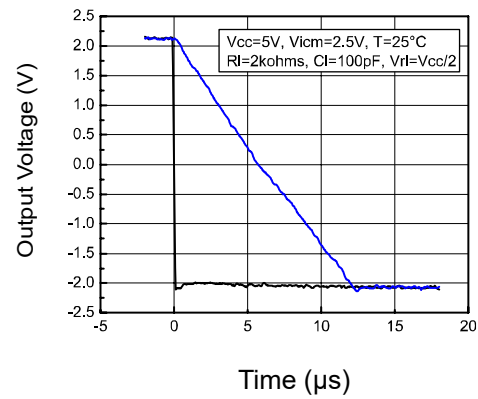


Figure 8: Negative slew rate vs. time

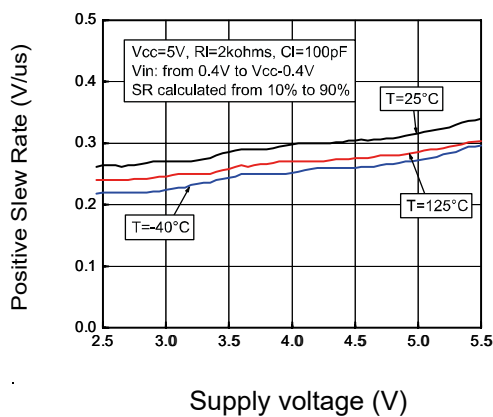


Figure 9: Positive slew rate vs. supply voltage

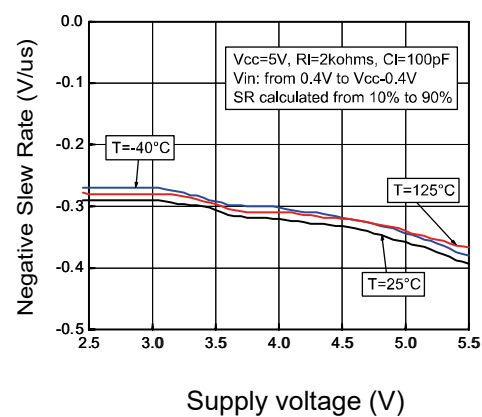
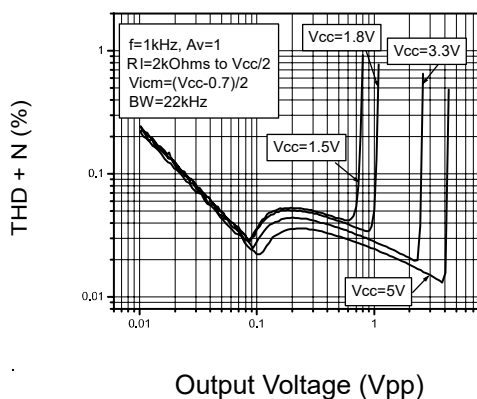
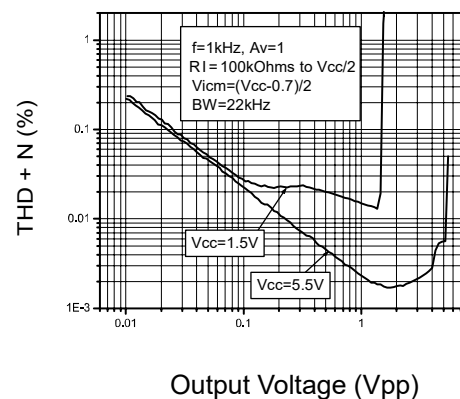


Figure 10: Negative slew rate vs. supply voltage

Figure 11: Distortion + noise vs. output voltage  
( $R_L=2k\Omega$ )Figure 12: Distortion + noise vs. output voltage  
( $R_L=100k\Omega$ )



### 8.3 Typical characteristic

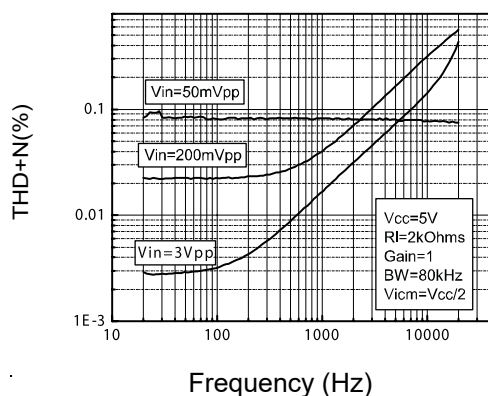


Figure 13: Distortion + noise vs. frequency and input voltage

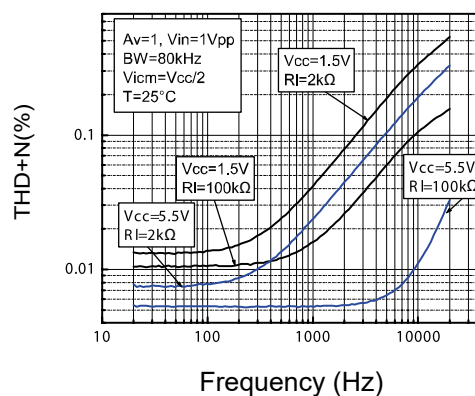


Figure 14: Distortion + noise vs. frequency and output load resistor

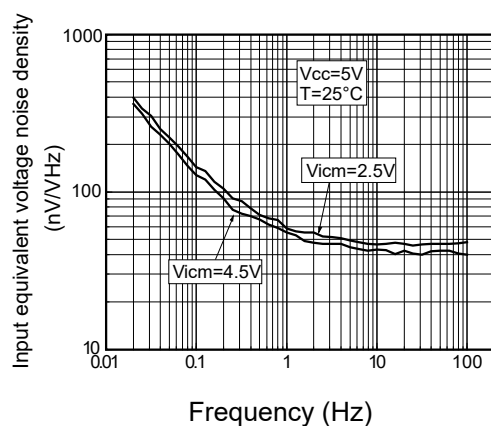


Figure 15: Noise vs. frequency

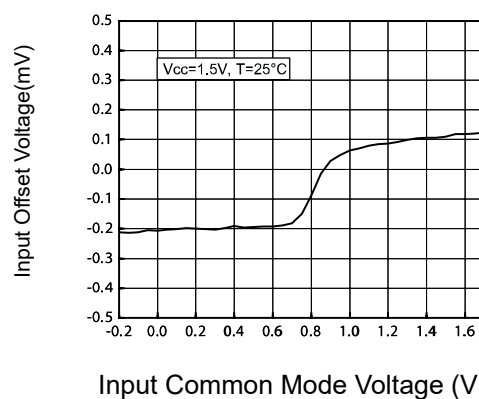


Figure 16: Input offset voltage vs input common mode at  $V_{CC}=1.5V$

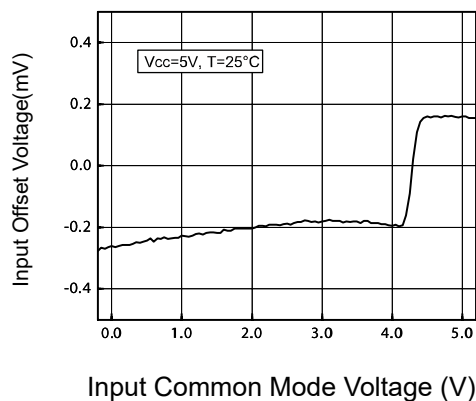


Figure 17: Input offset voltage vs input common mode at  $V_{CC}=5V$

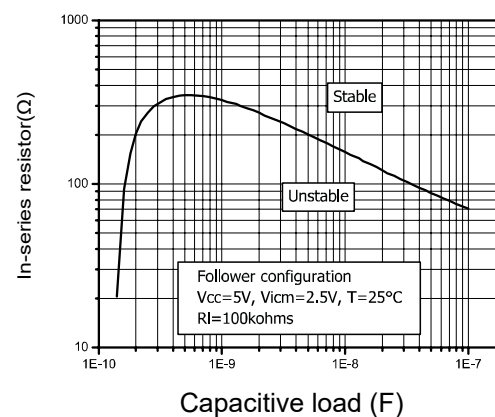
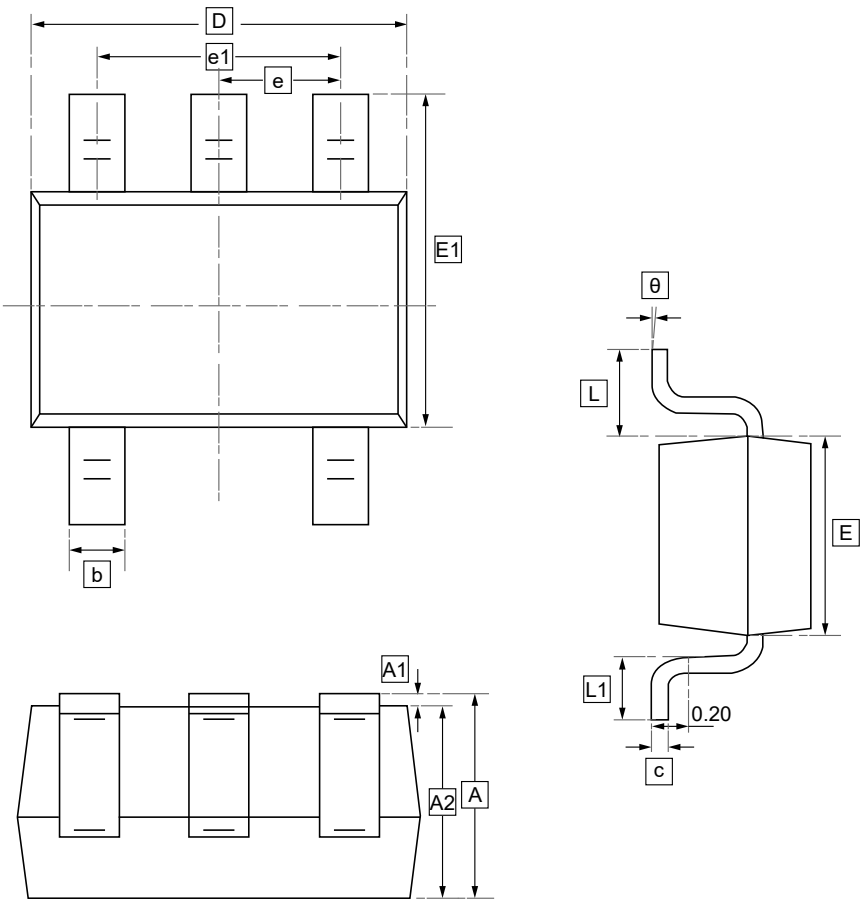


Figure 18: In-series resistor vs. capacitive load



Rail-to-rail input/output, 60  $\mu$ A, 880 kHz, 5V  
CMOS operational amplifiers

9.1 SC70-5 Package Outline Dimensions



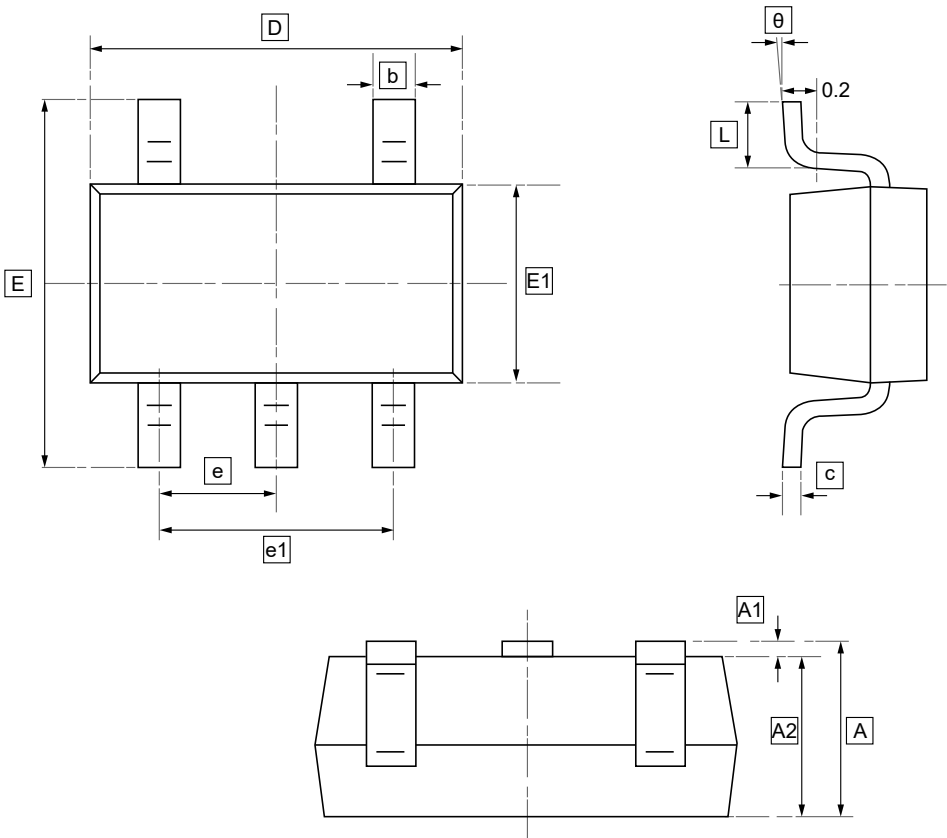
DIMENSIONS (mm are the original dimensions)

| Symbol | A    | A1   | A2   | b    | c    | D    | E    | E1   | e    | e1   | L    | θ    |
|--------|------|------|------|------|------|------|------|------|------|------|------|------|
| Min    | 0.90 | 0.00 | 0.90 | 0.15 | 0.08 | 2.05 | 1.15 | 2.15 | 0.65 | 1.20 | 0.26 | 7°   |
| Max    | 1.10 | 0.10 | 1.00 | 0.35 | 0.15 | 2.25 | 1.35 | 2.45 | TYP  | 1.40 | 0.46 | REF. |



Rail-to-rail input/output, 60  $\mu$ A, 880 kHz, 5V  
CMOS operational amplifiers

9.2 SOT-23-5 Package Outline Dimensions



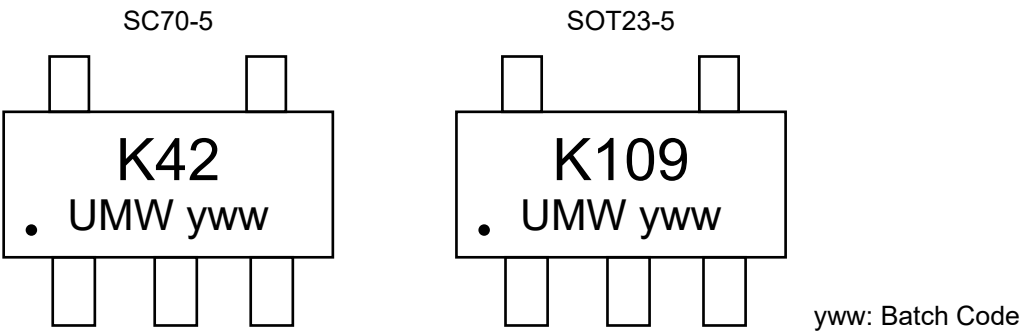
DIMENSIONS (mm are the original dimensions)

| Symbol | A     | A1    | A2    | b     | c     | D     | E1    | E     | e     | e1    | L     | $\theta$ |
|--------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|----------|
| Min    | 1.050 | 0.000 | 1.050 | 0.300 | 0.100 | 2.820 | 1.500 | 2.650 | 0.950 | 1.800 | 0.300 | 0°       |
| Max    | 1.250 | 0.100 | 1.150 | 0.500 | 0.200 | 3.020 | 1.700 | 2.950 | BSC   | 2.000 | 0.600 | 8°       |



Rail-to-rail input/output, 60  $\mu$ A, 880 kHz, 5V  
CMOS operational amplifiers

10.Ordering information



| Order Code     | Marking | Package | Base QTY | Delivery Mode |
|----------------|---------|---------|----------|---------------|
| UMW TSV631ICT  | K19     | SC70-5  | 3000     | Tape and reel |
| UMW TSV631AICT | K42     | SC70-5  | 3000     | Tape and reel |
| UMW TSV631AILT | K142    | SOT23-5 | 3000     | Tape and reel |
| UMW TSV631ILT  | K109    | SOT23-5 | 3000     | Tape and reel |



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